VS-E5TH3006-M3

RoHS

COMPLIANT

Vishay Semiconductors

Hyperfast Rectifier, 30 A FRED Pt[®] G5



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LINKS TO ADDITIONAL RESOURCES



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PRIMARY CHARACTERISTICS						
I _{F(AV)}	30 A					
V _R	600 V					
V _F at I _F at 125 °C	1.15 V					
t _{rr} (typ.)	25 ns					
T _J max.	175 °C					
Package	2L TO-220AC					
Circuit configuration	Single					

FEATURES

- Best in class forward voltage drop and switching losses trade off
- Optimized for high speed operation
- 175 °C maximum operating junction temperature
- Polyimide passivation
- Meets JESD 201 class 1A whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Featuring a unique combination of low conduction and switching losses, this rectifier is the right choice for soft switched and resonant converters, as well as medium frequency hard switching converters. This device is specifically designed to improve efficiency of high speed LLC output rectification stages of EV / HEV battery charging stations and high frequency stages of UPS applications.

MECHANICAL DATA

Case: 2L TO-220AC

Molding compound meets UL 94 V-0 flammability rating

Terminals: matte tin plated leads, solderable per J-STD-002

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ABSOLUTE MAXIMUM RATINGS								
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS				
Repetitive peak reverse voltage	V _{RRM}		600	V				
Average rectified forward current	I _{F(AV)}	T _C = 113 °C, D = 0.50	30	А				
Repetitive peak forward current	I _{FRM}	T _C = 113 °C, D = 0.50, f = 20 kHz	60					
Non-repetitive peak surge current	I _{FSM}	T_{C} = 25 °C, t_{p} = 10 ms, sine wave	330					
Operating junction and storage temperature	T _J , T _{Stg}		-55 to +175	°C				

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)								
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-			
Forward voltage	V _F	I _F = 30 A	-	1.3	1.6	V		
i orward voltage		I _F = 30 A, T _J = 125 °C	-	1.15	-			
Deverse leekese eurrent	1	V _R = V _R rated	-	-	20			
Reverse leakage current	IR	$T_J = 125 \text{ °C}, V_R = V_R \text{ rated}$	-	-	500	μA		
Junction capacitance	CT	V _R = 200 V	-	36	-	pF		
Series inductance	L _S	Measured to lead 5 mm from package body	-	8	-	nH		

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DYNAMIC RECOVERY O	HARACTERI	STICS (T _J = 25	°C unless otherwi	se speci [.]	fied)		
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS	
		I _F = 1.0 A,dI _F /dt =	100 A/ μ s, V _R = 30 V	-	25	-	
Reverse recovery time	t _{rr}	T _J = 25 °C		-	41	-	ns
		T _J = 125 °C		-	58	-	
Deals receivers aurrent		T _J = 25 °C I _F = 20 A dl _F /dt = 1000 A/µs	-	19	-		
Peak recovery current	I _{RRM}	T _J = 125 °C	$V_{\rm R} = 400 \text{V}$	-	32	-	A
	0	T _J = 25 °C		-	419	-	nC
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1176	-	
		T _J = 25 °C		-	46	-	ns
Reverse recovery time	t _{rr}	T _J = 125 °C		-	65	-	
Deck receiver aurrent		T _J = 25 °C	$I_F = 30 A$	-	21	-	A
Peak recovery current	IRRM	T _J = 125 °C	dI _F /dt = 1000 A/µs V _B = 400 V	-	36	-	
		T _J = 25 °C		-	550	-	
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	1560	-	nC

THERMAL - MECHANICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS			
Thermal resistance, junction-to-case	R _{thJC}		-	-	1.3	°C/W			
Weight			-	2.0	-	g			
weight			-	0.07	-	oz.			
Mounting torque			6.0 (5.0)	-	12 (10)	kgf · cm (lbf · in)			
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C			
Marking device		Case style 2L TO-220AC	E5TH3006						

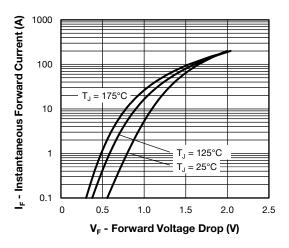


Fig. 1 - Forward Voltage Drop Characteristics, Per Leg

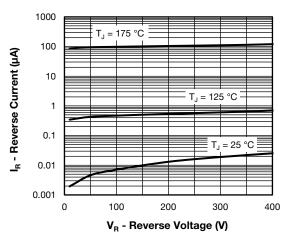


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage, Per Leg

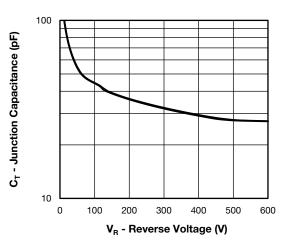
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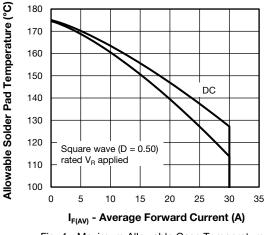
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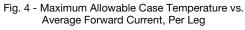


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Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage, Per Leg





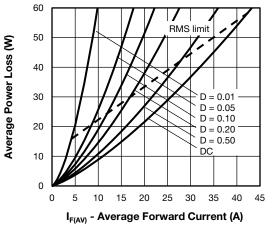


Fig. 5 - Forward Power Loss Characteristics, Per Leg

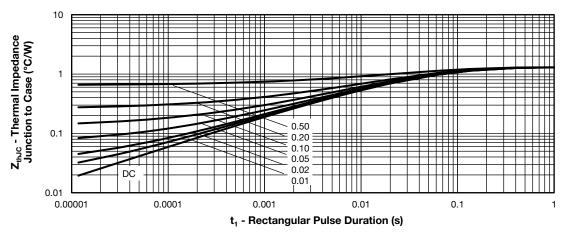


Fig. 6 - Transient Thermal Impedance, Junction to Case, Per Leg

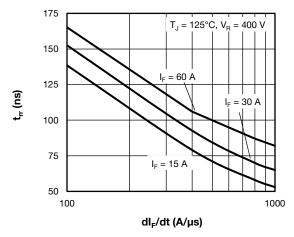
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Fig. 7 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg

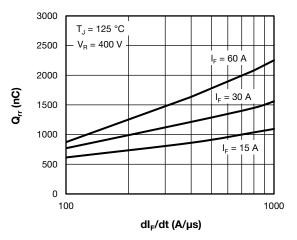


Fig. 8 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg

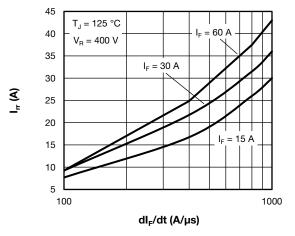


Fig. 9 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg

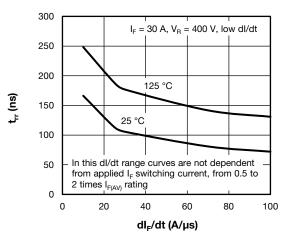


Fig. 10 - Typical Reverse Recovery Time vs. dl_F/dt, Per Leg

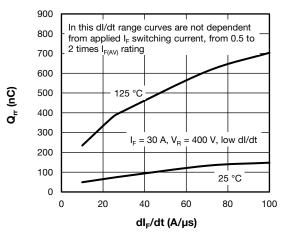


Fig. 11 - Typical Reverse Recovery Charge vs. dl_F/dt, Per Leg

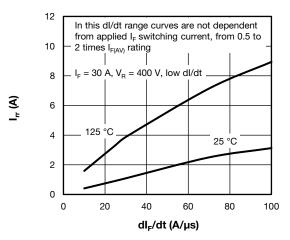


Fig. 12 - Typical Reverse Recovery Current vs. dl_F/dt, Per Leg

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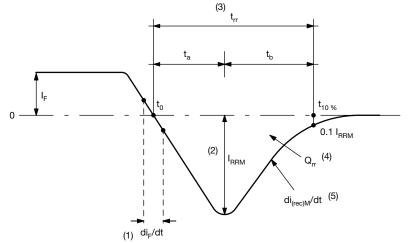


Fig. 13 - Reverse Recovery Waveform and Definitions

Notes

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 $^{(1)}$ di_F/dt - rate of change of current through zero crossing

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- ⁽²⁾ I_{RRM} peak reverse recovery current
- (3) t_{rr} reverse recovery time measured from t_0 , crossing point of negative going I_F , to point $t_{10\%}$, 0.1 I_{RRM}
- $^{(4)}$ Qrr area under curve defined by t_0 and $t_{10\ \%}$

$$Q_{rr} = \int_{t_0}^{t_{10}\%} I(t)dt$$

 $^{(5)}$ di_(rec)M/dt - peak rate of change of current during t_b portion of t_{rr}

ORDERING INFORMATION TABLE

1 2 3 4 5 6 7 8 1 - Vishay Semiconductors product 2 - $E = single diode$ 3 - 5 = FRED generation 5
 I - Vishay Semiconductors product 2 - E = single diode
2 - E = single diode
3 - 5 = FBED generation 5
G THE gonoration of
4 - Package: T = 2L TO-220AC
5 - H = hyperfast recovery
6 - Current rating (30 = 30 A)
7 - Voltage rating (06 = 600 V)
8 - Environmental digit:
-M3 = halogen-free, RoHS-compliant, and termi

ORDERING INFORMATION (Example)								
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION					
VS-E5TH3006-M3	50	1000	Antistatic plastic tube					

LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96156				
Part marking information	www.vishay.com/doc?95391				
SPICE model	www.vishay.com/doc?96919				

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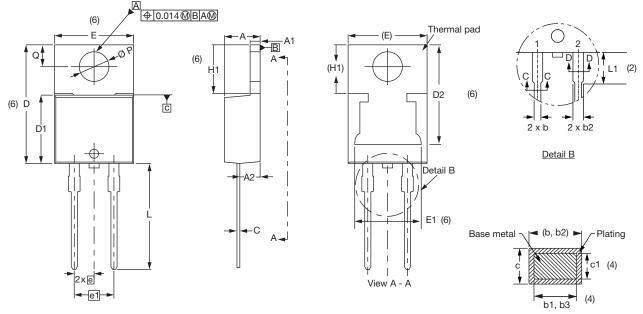


Outline Dimensions

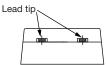
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2L TO-220AC

DIMENSIONS in millimeters and inches



Section C - C and D - D



Conforms t	to JEDEC®	outline	TO-220AC
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SYMBOL	MILLIMETERS		INCHES		NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.25	4.65	0.167	0.183		
A1	1.14	1.40	0.045	0.055		
A2	2.50	2.92	0.098	0.115		
b	0.69	1.01	0.027	0.040		
b1	0.38	0.97	0.015	0.038	4	
b2	1.20	1.73	0.047	0.068		
b3	1.14	1.73	0.045	0.068	4	
с	0.36	0.61	0.014	0.024		
c1	0.36	0.56	0.014	0.022	4	
D	14.85	15.35	0.585	0.604	3	
D1	8.38	9.02	0.330	0.355		

SYMBOL	MILLIN	IETERS	INC	HES	NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	11.68	13.30	0.460	0.524	6, 7
E	10.11	10.51	0.398	0.414	3, 6
E1	6.86	8.89	0.270	0.350	6
e	2.41	2.67	0.095	0.105	
e1	4.88	5.28	0.192	0.208	
H1	6.09	6.48	0.240	0.255	6
L	13.52	14.02	0.532	0.552	
L1	3.32	3.82	0.131	0.150	2
ØР	3.54	3.91	0.139	0.154	
Q	2.60	3.00	0.102	0.118	

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

(2) Lead dimension and finish uncontrolled in L1

⁽³⁾ Dimension D, D1, and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Dimension b1, b3, and c1 apply to base metal only

⁽⁵⁾ Controlling dimensions: inches

⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2, and E1

⁽⁷⁾ Outline conforms to JEDEC[®] TO-220, except D2

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